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(54) Title: POLYAMIDEIMIDESILOXANE HOT MELT ADHESIVE

(57) Abstract

A solution of a hot melt adhesive which comprises an organic solvent and a fully imidized polyamideimidesiloxane is disclosed wherein 0.5 to 30 mole% of the dianhydride or diamine monomers are siloxane containing monomers. Up to 50 mole% of the diamine monomer is aliphatic diamine that contains neither siloxane groups nor amide linkages and 40 to 99 mole% is aromatic diamine that does not contain siloxane groups. The aromatic diamine is (1) 20 to 100 mole% unsymmetrical aromatic diamine having at least two aromatic rings, two amine groups on different aromatic rings, and contains an amide linkage in the chain and (2) up to 50 mole% of aromatic diamine that contains neither siloxane groups nor amide linkages. A tape can be made from the solutions and an article can be attached to a substrate by applying the tape to the substrate or the article.

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POLYAMIDEIMIDESILOXANE HOT MELT ADHESIVE

This invention relates to a polyamideimidesiloxane and to its use as a hot melt adhesive.

Polyamideimidesiloxanes have been disclosed for use as hot melt adhesives for microelectronic assembly. A solution is formed of the polyamic acid precursor, the solution is applied to a substrate, the solvent is evaporated, and the polyamic acid is imidized on the substrate.

According to a first aspect of this invention there is provided a solution of a hot melt adhesive comprising

- (I) an organic solvent; and
- (II) a fully imidized polyamideimidesiloxane which comprises the reaction product of dianhydride monomer with diamine monomer, where
 - (A) about 0.5 to about 30 mole% of said monomers contain siloxane groups and are siloxane dianhydrides having the

general formula

$$O \longrightarrow R_{2} \longrightarrow \begin{bmatrix} R \\ | \\ Si - O \end{bmatrix} \longrightarrow \begin{bmatrix} R \\ | \\ Si - R_{2} \end{bmatrix} \longrightarrow \begin{bmatrix} O \\ | \\ C \\ | \\ R \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow \begin{bmatrix} C \\ C \\ | \\ C \end{bmatrix} \longrightarrow 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or siloxane diamines having the general formula

$$H_2N-R_1 = \begin{bmatrix} R \\ | \\ Si-O \end{bmatrix} = \begin{bmatrix} R \\ | \\ Si-R_1-NH_2 \\ | \\ R \end{bmatrix}$$

or mixtures thereof, where R, R_1 , and R_2 are mono, di, and triradicals, respectively, each independently selected from a substituted or unsubstituted 1 to 12 carbon atom aliphatic group or a substituted or unsubstituted 6 to 10 carbon atom aromatic group, and m is 1 to 200;

(B) up to about 50 mole%, based on said diamine monomer, of aliphatic diamine that contains neither siloxane groups nor amide linkages; and

- (C) about 40 to about 99 mole%, based on said diamine monomer, of aromatic diamine that does not contain siloxane groups, selected from the group consisting of
 - (1) about 20 to about 100 mole%, based on said aromatic diamine, of unsymmetrical aromatic diamine that has at least two aromatic rings, two amine groups on different aromatic rings, and contains at least one amide linkage in its chain; and
 - (2) up to about 50 mole%, based on said aromatic diamine, of aromatic diamine that contains neither siloxane groups nor amide linkages.

The invention also provides a method of making a tape comprising forming a coating by applying a solution according to the first aspect of the invention to a film and evaporating said organic solvent from said solution.

The film may be a release film and the coating may be removed from the release film. The coating may be about 15 to about 50 µm thick. The solution may be applied to both sides of the film producing a three-layered tape.

Thus the invention provides a method of attaching an article to a substrate

comprising placing said article or said substrate against one side of a tape made according to the method described immediately above, heating said tape above its softening point, and pressing said substrate or said article, respectively, against the other side of the tape.

This invention also provides a solution of a hot melt adhesive comprising

- (I) an organic solvent; and
- (II) about 10 to about 40 wt% of a fully imidized polyamideimidesiloxane which comprises the reaction product of
 - (A) dianhydride selected from the group consisting of 4,4'oxydiphthalic anhydride, bisphenol A dianhydride, and
 mixtures thereof; and
 - (B) diamine which comprises
 - (1) about 1 to about 20 mole%, based on moles of monomer, of siloxane diamine having the general formula

$$H_2N-R_1 = \begin{bmatrix} R \\ | \\ Si-O \end{bmatrix} = \begin{bmatrix} R \\ | \\ Si-R_1-NH_2 \\ | \\ R \end{bmatrix}$$

where R is alkyl from C_1 to C_4 , R_1 is alkylene from C_1 to C_4 , and m is 1 to 12; and

about 80 to about 99 mole%, based on total diamine monomer, of aromatic diamine selected from the group consisting of 3,3'-diaminobenzanilide, 4,3'-diaminobenzanilide, 3,4'-diaminobenzanilide, and mixtures thereof.

Additionally the invention provides a solution of a hot melt adhesive comprising

- (I) an organic solvent selected from the group consisting of N-methyl pyrrolidinone, dimethylacetamide, dimethyl formamide, and tetrahydrofuran;
- (II) about 20 to about 30 wt% of a fully imidized polyamideimidesiloxane which comprises the reaction product of
 - (A) a dianhydride selected from the group consisting of 4,4'-oxydiphthalic anhydride, bisphenol A dianhydride, and mixtures thereof; and
 - (B) diamine which comprises
 - (1) about 1 to about 20 mole%, based on moles of monomer, of siloxane diamine having the general formula; and

$$\begin{array}{cccc} CH_3 & CH_3 \\ | & | \\ H_2N^-(CH_2)_3 - Si^-O - Si^-(CH_2)_3 - NH_2 \\ | & | \\ CH_3 & CH_3 \end{array}$$

about 80 to about 99 mole%, based on diamine monomer, of aromatic diamine selected from the group consisting of 3,3'-diaminobenzanilide, 3,4'-diaminobenzanilide, 4,3'-diaminobenzanilide, and mixtures thereof.

An excellent adhesive for bonding microelectronic components can be made from a polyamideimidesiloxane, where the aromatic diamine that forms the amide linkages is unsymmetrical. In the adhesive of this invention a solution is formed of a fully imidized polyamideimidesiloxane so that very little imidization occurs on the substrate - there is no imidization step on the assembly line. The adhesive of this invention may form a good fillet around components pressed into it.

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The preferred polyamideimidesiloxane of this invention is the reaction product of a dianhydride monomer with a primary diamine monomer. Any dianhydride or combination of dianhydrides can be used as the dianhydride monomer, although aromatic dianhydrides are preferred as they give superior properties. Examples of suitable dianhydrides include:

- 1,2,5,6-naphthalene tetracarboxylic dianhydride;
- 1,4,5,8-naphthalene tetracarboxylic dianhydride;
- 2,3,6,7-naphthalene tetracarboxylic dianhydride;
- 2-(3',4'-dicarboxyphenyl) 5,6-dicarboxybenzimidazole dianhydride;
- 2-(3',4'-dicarboxyphenyl) 5,6-dicarboxybenzoxazole dianhydride;
- 2-(3',4'-dicarboxyphenyl) 5,6-dicarboxybenzothiazole dianhydride;
- 2,2',3,3'-benzophenone tetracarboxylic dianhydride;
- 2,3,3',4'-benzophenone tetracarboxylic dianhydride;
- 3,3',4,4'-benzophenone tetracarboxylic dianhydride (BTDA);
- 2,2',3,3'-biphenyl tetracarboxylic dianhydride;
- 2,3,3',4'-biphenyl tetracarboxylic dianhydride;
- 3,3',4,4'-biphenyl tetracarboxylic dianhydride (BPDA);
- bicyclo-[2,2,2]-octen-(7)-2,3,5,6-tetracarboxylic-2,3,5,6-

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dianhydride;
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thio-diphthalic anhydride;

bis(3,4-dicarboxyphenyl) sulfone dianhydride;

bis(3,4-dicarboxyphenyl) sulfoxide dianhydride;

bis(3,4-dicarboxyphenyl oxadiazole-1,3,4) paraphenylene dianhydride;

bis(3,4-dicarboxyphenyl) 2,5-oxadiazole 1,3,4-dianhydride;

bis[2,5-(3',4'-dicarboxydiphenylether)] 1,3,4-oxadiazole dianhydride;

bis(3,4-dicarboxyphenyl) ether dianhydride or 4,4'oxydiphthalic anhydride (ODPA);

bis(3,4-dicarboxyphenyl) thioether dianhydride;

ethylene glycol bis(anhydro-trimellitate);

5,5'-(1-

methylethylidene)bis(1,3-isobenzofurandione)or 4,4'[isopropylidene bis(p-phenyleneoxy)]diphthalic anhydride or bisphenol A dianhydride (BPADA);

bisphenol S dianhydride;

2,2-bis(3,4-dicarboxyphenyl) hexafluoropropane dianhydride or 5,5-[2,2,2-trifluoro-1-(trifluoromethyl)ethylidene] bis(1,3-isobenzofurandione) (6FDA);

10

hydroquinone bisether dianhydride;
bis (3,4-dicarboxyphenyl) methane dianhydride;
cyclopentadienyl tetracarboxylic acid dianhydride;
cyclopentane tetracarboxylic dianhydride;
ethylene tetracarboxylic acid dianhydride;
perylene 3,4,9,10-tetracarboxylic dianhydride;
pyromellitic dianhydride (PMDA);
tetrahydrofuran tetracarboxylic dianhydride; and
resorcinol dianhydride.

The preferred dianhydrides are ODPA and BPADA as polyamideimidesiloxanes made from them are more soluble. The dianhydrides can be used in the tetraacid form or as mono, di, tri, or tetraesters of the tetraacid, but the dianhydride form is preferred as it is more reactive.

About 0.5 to about 30 mole% of the monomers used to make the polyamideimidesiloxane contain siloxane groups. If more or less siloxane monomer is used, the polymer may have less adhesion. Preferably, about 1 to about 20 mole% of the monomers contain siloxane groups. The siloxane-containing monomer can be either a siloxane dianhydride or a siloxane diamine or a mixture thereof, but siloxane diamines are preferred as they are

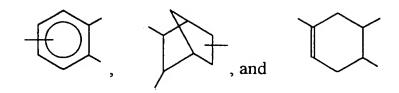
commercially available and less expensive. Examples of siloxane-containing diamines that can be used have the formula

$$H_2N-R_1 = \begin{bmatrix} R \\ | \\ Si-O \end{bmatrix} - \begin{bmatrix} R \\ | \\ Si-R_1-NH_2 \\ | \\ R \end{bmatrix}$$

Examples of siloxane-containing dianhydrides that can be used have formula

where R, R₁, and R₂ are mono, di, and triradicals, respectively, each independently selected from a substituted or unsubstituted 1 to 12 carbon atom aliphatic group or a substituted or unsubstituted 6 to 10 carbon atom aromatic group and m is 1 to 200. Examples of monoradicals include -CH₃, -CF₃, -CH=CH₂, -(CH₂)_nCF₃, -C₆H₅, -CF₂-CHF-CF₃, and -CH₂-CH₂-CO-O-CH₂CF₂CF₂CF₃. Examples of diradicals include -(CH₂)_n-, -(CH₂)_nCF₂- and -C₆H₄-, where n is 1 to 10. Examples of triradicals include =CH-CH₂-,

12



R and R_1 are preferably aliphatic from C_1 to C_{10} and more preferably R is alkyl from C_1 to C_4 and R_1 is alkylene from C_1 to C_4 . Still more preferably, R is methyl and R_1 is propyl; m is preferably 1 to 12 and is most preferably 1. The preferred siloxane diamines form more flexible coatings and films. Preferred siloxane diamines are herein referred to as " G_m ."

For good thermal stability, about 40 to about 99 mole% of the non-siloxane diamine monomers are aromatic diamine monomers, and preferably about 80 to about 99 mole% of the non-siloxane diamine monomers are aromatic diamines. About 20 to about 100 mole% of the non-siloxane aromatic diamine is an unsymmetrical aromatic diamine.

The unsymmetrical aromatic diamine has at least two aromatic rings, two amine group attached to different aromatic rings, at least one amide group in its chain, and is unsymmetrical. "Unsymmetrical" means that at least one of the amine groups is ortho or meta or, if both amine groups are para, that there are other aromatic substitutions so that when the two amine groups are reacted

with dianhydrides to form two imide groups, the structure on one side of a line joining those two imide groups is not identical to the structure on the other side of the line (ignoring the amide group). This unsymmetrical structure is required to make the polymer soluble after it has been fully imidized. Examples of unsymmetrical aromatic diamines include 3,3'-diaminobenzanilide (3.3'-DABAN). 4,3'-diaminobenzanilide (4,3'DABAN). 3,4'diaminobenzanilide, isophthal (3-aminoanilide), isophthal (4-aminoanilide), terphthal (3-aminoanilide), N,N'-m-phenylene-bis(3-aminobenzamide), and N,N'-m-phenylene-bis(4-aminobenzamide); 4,4'-diaminobenzanilide is an example of a symmetrical aromatic diamine. The three benzanilide diamines are because they form more soluble polymers: 3,3'diaminobenzanilide is especially preferred.

While preferably all of the non-siloxane aromatic diamine monomer is the unsymmetrical aromatic diamine, up to about 50 mole% of the aromatic diamine monomer can be aromatic diamine that contains neither a siloxane group nor an amide linkage. Examples of such diamines include 3,4'-oxydianiline, 4',3-oxydianiline, 3,3'-oxydianiline, 1,3'-bis(3-amino phenoxy)benzene (APB), and 2,2'-bis(4[4-aminophenoxy]phenyl propane (BAPP).

14

Preferably, no aliphatic diamine is present (other than siloxane-containing diamine), but up to about 50 mole% of the diamine monomer can be aliphatic diamine that contains neither a siloxane group nor an amide linkage. Examples of such diamines include $H_2N(CH_2)_pNH_2$ and $H_2N(CH_2-CHCH_3-O)_p$ -CHCH₃-NH₂, where p is 4 to 100. Another example is a 36 carbon diamine having 2 terminal primary amine groups sold by Henkel Corporation as "Versamine 552."

While it is preferably not used, up to about 10 mole% (based on moles of polymer) of an end capper, such as trimellitic anhydride or phthalic anhydride, can be included to control molecular weight.

The polyamideimidesiloxane is prepared by forming a solution in an organic solvent of dianhydride and diamine monomers. Stoichiometric proportions, ±5 mole%, can be used. Examples of suitable solvents include N-methyl pyrrolidinone (NMP), dimethylacetamide, dimethyl formamide, tetrahydrofuran, diglyme, triglyme, and y-butyrolactone. NMP is preferred because the polymers are more soluble in it and it forms a good film. The solution should be about 10 to about 40 wt% solids as it is difficult to form a solution with less solvent and more solvent is usually unnecessary. Preferably, the solution is about 20 to about 30 wt% solvent.

When the monomers are mixed together at room temperature (RT) a polyamic acid forms in an exothermic reaction. About 20 to about 40 wt% (based on solvent weight) of a refluxing solvent, such as toluene or xylene, is added to the solution of the polyamic acid and the solution is refluxed for several hours to fully imidize the polyamideimidesiloxane. The polymer is fully imidized when at least 90% of the amic acid groups have imidized. This solution should be about 10 to about 40 wt% polyamideimidesiloxane and is preferably about 20 to about 30 wt% polyamideimidesiloxane.

The solution of the fully imidized polyamideimidesiloxane is cooled and is applied to a substrate. Suitable substrates include polyimide film, copper film, aluminum film, and other metal films. One or both sides of the substrate can be coated to form a lead-on-chip (LOC) tape. Alternatively, a release film, such as a polyester film, can be coated on one side so that, after evaporation of the solvent, an adhesive polyamideimidesiloxane film can be pulled off the release film. Baking at a temperature of about 200 to about 250°C will remove the solvent. The coating or the free-standing film is preferably about 10 to about 100 µm thick. It is non-tacky and can be rolled up if desired.

The coating or film is heated above its softening point (typically 150 to 400°C) and the articles to be bonded are pressed against it. The adhesive is

16

useful in microelectronics fabrication for bonding articles such as semiconductor dies and lead frames. It is especially useful for making 3-layer LOC tapes. The lead fingers of a lead frame can be pressed into the adhesive on one side of the LOC tape and semiconductor dies can be pressed into the adhesive on the other side. When a device is pressed into the adhesive, a fillet or ridge of adhesive forms around the device to help secure it.

The following examples further illustrate this invention.

Example 1

A 3-necked glass reactor, equipped with a mechanical stirrer and a Dean & Stark receiver having a condenser, was purged with dry nitrogen. To this reactor was added with stirring 45.5 g (0.2 mol) 4,3'-DABAN 12.6 g (0.05 mol) 1,3-bis(3-aminopropyl)-1,1,3,3-tetramethylsiloxane (G₁) 400 g NMP, and 77.5 g (0.25 mol) ODPA. The mixture was polymerized at room temperature overnight, forming a polyamic acid. For azeotropic distillation, 100 g of toluene was added to the polyamic acid solution. The temperature was raised to 150°C for 3 to 4 hours to imidize the polyamic acid. After imidizaton, the toluene was distilled off.

17

The fully imidized resin was soluble in NMP at room temperature (RT). The resin solution was coated onto a polyester film and the solvent was dried at 230°C. The glass transition temperature (Tg) by Differential Scanning Calorimeter (DSC) was 244°C.

The resin solution was also coated onto both sides of "Upilex" or "Kapton" polyimide film and the NMP was removed at 230°C. The three-layer LOC tape was attached to an Alloy 42 lead frame at 370°C by hot pressing. Good fillets appeared around the lead fingers. The semiconductor die was attached to the other side of the tape on the lead frame at 400°C. Bonding to the chip surface and to the lead frame was excellent.

Examples 2 and 3

Copolyimides of ODPA with diaminobenzanilde isomers and G₁ were prepared using the procedure described in Example 1.

Example	Aromatic Diamine	mole% G₁	Tg, °C (DSC)	Solubility in NMP at RT
2	80 mole% 3,4'-DABAN	20	226	Soluble
3	90 mole% 3,3'-DABAN	10	232	Soluble

Each of the resin solutions was coated onto both sides of "Upilex" polyimide film and the solvent was driven out at 240°C. The 3-layer LOC tapes were

18

attached to Alloy 42 lead frame at 370°C by hot pressing. Good fillets appeared around the lead fingers. A semiconductor die was attached to the other side of the tape at 420°C. Both films showed good bonding to the chip and lead frame.

Example 4, 5, and 6

Copolyimides of BPADA with 80 mole% diaminobenzanilide isomers and G₁ were prepared using the procedure described in Example 1.

Example	Aromatic Diamine	mole% G₁	Tg, °C (DSC)	Solubility in NMP at RT
4	3,4'-DABAN	20	202	Soluble
5	3,3'-DABAN	20	192	Soluble
6	4,4'-DABAN	20		Not soluble

The solutions of Examples 4 and 5 were coated onto both sides of "Upilex" polyimide film and baked at 250°C to remove the solvent. The 3-layer adhesive films were attached to an Alloy 42 lead frame at 350°C by hot pressing. Good fillets appeared around the lead fingers. The semiconductor die was attached to the other side of the adhesive film at 400°C by hot pressing. The chip and lead frame had good adhesion to the adhesive film.

In the present specification "comprise" means "includes or consists of" and "comprising" means "including or consisting of".

The features disclosed in the foregoing description, or the following claims, or the accompanying drawings, expressed in their specific forms or in terms of a means for performing the disclosed function, or a method or process for attaining the disclosed result, as appropriate, may, separately, or in any combination of such features, be utilised for realising the invention in diverse forms thereof.

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CLAIMS:

- 1. A solution of a hot melt adhesive comprising
 - (l) an organic solvent; and
 - (II) a fully imidized polyamideimidesiloxane which comprises the reaction product of dianhydride monomer with diamine monomer, where
 - (A) about 0.5 to about 30 mole% of said monomers contain siloxane groups and are siloxane dianhydrides having the general formula

or siloxane diamines having the general formula

21

$$H_2N-R_1 = \begin{bmatrix} R \\ | \\ Si-O \end{bmatrix} - \begin{bmatrix} R \\ | \\ Si-R_1-NH_2 \end{bmatrix}$$

$$R$$

$$R$$

$$R$$

or mixtures thereof, where R, R₁, and R₂ are mono, di, and triradicals, respectively, each independently selected from a substituted or unsubstituted 1 to 12 carbon atom aliphatic group or a substituted or unsubstituted 6 to 10 carbon atom aromatic group, and m is 1 to 200;

- (B) up to about 50 mole%, based on said diamine monomer, of aliphatic diamine that contains neither siloxane groups nor amide linkages; and
- (C) about 40 to about 99 mole%, based on said diamine monomer, of aromatic diamine that does not contain siloxane groups, selected from the group consisting of
 - (1) about 20 to about 100 mole%, based on said aromatic diamine, of unsymmetrical aromatic

22

diamine that has at least two aromatic rings, two amine groups on different aromatic rings, and contains at least one amide linkage in its chain; and

- (2) up to about 50 mole%, based on said aromatic diamine, of aromatic diamine that contains neither siloxane groups nor amide linkages.
- 2. A solution according to Claim 1 wherein said dianhydride monomer is 4,4'-oxydiphthalic anhydride.
- 3. A solution according to Claim 1 wherein said dianhydride monomer is bisphenol A dianhydride.
- 4. A solution according to any one of the preceding Claims wherein m is 1 to 12.
- 5. A solution according to any one of the preceding Claims wherein R is CH₃.
- 6. A solution according to any one of Claims 1 to 5 wherein R_1 is $-(CH_2)_3$ -.

- 7. A solution according to any one of the preceding Claims wherein said unsymmetrical aromatic diamine is 3,3'-diaminobenzanilide.
- 8. A solution according to any one of Claims 1 to 6 wherein said unsymmetrical aromatic diamine is 3,4'-diaminobenzanilide.
- 9. A solution according to any one of Claims 1 to 6 wherein said unsymmetrical aromatic diamine is 4,3'-diaminobenzanilide.
- 10. A solution according to any one of the preceding Claims wherein said organic solvent is N-methyl pyrrolidinone.
- 11. A method of making a tape comprising forming a coating by applying a solution according to any one of Claims 1 to 10 to a film and evaporating said organic solvent from said solution.
- 12. A method according to Claim 11 wherein said film is a release film and said coating is removed from said release film.
- 13. A method according to Claim 11 or 12 wherein said coating is about 15 to about 50 µm thick.

- 14. A method according to Claim 11, 12 or 13 wherein said solution is applied to both sides of said film, producing a three-layer tape.
- 15. A method of attaching an article to a substrate comprising placing said article or said substrate against one side of a tape made according to the method of Claim 14, heating said tape above its softening point, and pressing said substrate or said article, respectively, against the other side of said tape.
- 16. A solution of a hot melt adhesive comprising
 - (I) an organic solvent; and
 - (II) about 10 to about 40 wt% of a fully imidized polyamideimidesiloxane which comprises the reaction product of
 - (A) dianhydride selected from the group consisting of 4,4'oxydiphthalic anhydride, bisphenol A dianhydride, and
 mixtures thereof; and
 - (B) diamine which comprises

(1) about 1 to about 20 mole%, based on moles of monomer, of siloxane diamine having the general formula

$$H_2N-R_1 = \begin{bmatrix} R \\ | \\ Si-O \end{bmatrix} - \begin{bmatrix} R \\ | \\ Si-R_1-NH_2 \\ | \\ R \end{bmatrix}$$

where R is alkyl from C_1 to C_4 , R_1 is alkylene from C_1 to C_4 , and m is 1 to 12; and

- (2) about 80 to about 99 mole%, based on total diamine monomer, of aromatic diamine selected from the group consisting of 3,3'-diaminobenzanilide, 4,3'-diaminobenzanilide, 3,4'-diaminobenzanilide, and mixtures thereof.
- 17. A solution according to Claim 16 wherein said aromatic diamine is 3,3'-diaminobenzanilide.
- 18. A solution according to Claim 16 or 17 wherein said solvent is N-methyl pyrrolidinone.

- 19. A solution according to Claim 16, 17 or 18 wherein said dianhydride is bisphenol A dianhydride.
- 20. A solution of a hot melt adhesive comprising
 - (I) an organic solvent selected from the group consisting of N-methyl pyrrolidinone, dimethylacetamide, dimethyl formamide, and tetrahydrofuran;
 - (II) about 20 to about 30 wt% of a fully imidized polyamideimidesiloxane which comprises the reaction product of
 - (A) a dianhydride selected from the group consisting of 4,4'oxydiphthalic anhydride, bisphenol A dianhydride, and
 mixtures thereof; and
 - (B) diamine which comprises
 - (1) about 1 to about 20 mole%, based on moles of monomer, of siloxane diamine having the general formula

$$CH_3$$
 CH_3 $H_2N-(CH_2)_3-Si-O-Si-(CH_2)_3-NH_2$ CH_3 CH_3 CH_3

; and

(2) about 80 to about 99 mole%, based on diamine monomer, of aromatic diamine selected from the group consisting of 3,3'-diaminobenzanilide, 3,4'-diaminobenzanilide, 4,3'-diaminobenzanilide, and mixtures thereof.

INTERNATIONAL SEARCH REPORT

Inter. July Application No PCT/GB 99/03719

A. CLASSIFICATION OF SUBJECT MATTER IPC 7 C09J179/08 C08G C08G73/10 C08G73/14 According to International Patent Classification (IPC) or to both national classification and IPC **B. FIELDS SEARCHED** Minimum documentation searched (classification system followed by classification symbols) IPC 7 C09J C08G Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) C. DOCUMENTS CONSIDERED TO BE RELEVANT Citation of document, with indication, where appropriate, of the relevant passages Category ° Relevant to claim No. Α US 5 739 263 A (T. YOSHIDA ET AL.) 1-20 14 April 1998 (1998-04-14) claims Α US 5 212 279 A (Y. NOMURA ET AL.) 1 18 May 1993 (1993-05-18) column 9, line 55 -column 10, line 17; claims; examples 2,8 Α US 4 960 846 A (M. BURGESSET AL.) 1-6.2 October 1990 (1990-10-02) 16-20 claims Further documents are listed in the continuation of box C. X X Patent family members are listed in annex. Special categories of cited documents : "T" later document published after the international filing date "A" document defining the general state of the art which is not considered to be of particular relevance or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention earlier document but published on or after the international "X" document of particular relevance; the claimed invention filing date cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "Y" document of particular relevance; the claimed invention cannot be particular relevance; the claimed invertion cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art. "O" document referring to an oral disclosure, use, exhibition or document published prior to the international filing date but later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 18 February 2000 29/02/2000 Name and mailing address of the ISA Authorized officer European Patent Office, P.B. 5818 Patentiaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040. Tx. 31 651 epo ni, Boeker, R Fax: (+31-70) 340-3016

1

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INTERNATIONAL SEARCH REPORT

Inter anal Application No
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C.(Continu	ation) DOCUMENTS CONSIDERED TO BE RELEVANT	PCI/GB 99/03/19
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